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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# International Rectifier

# 30WQ03FN

# **SCHOTTKY RECTIFIER**

3.5 Amp

$$I_{F(AV)} = 3.5 Amp$$
  
 $V_R = 30 V$ 

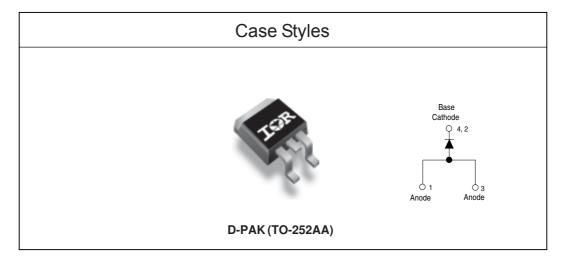
#### **Major Ratings and Characteristics**

Characteristics	Values	Units
I <sub>F(AV)</sub> Rectangular waveform	3.5	А
V <sub>RRM</sub>	30	V
I <sub>FSM</sub> @tp=5 µs sine	535	Α
V <sub>F</sub> @3 Apk, T <sub>J</sub> = 125°C	0.35	V
T <sub>J</sub> range	-40 to 150	°C

#### **Description/ Features**

The 30WQ03FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





# Voltage Ratings

Part number	30WQ03FN	
V <sub>R</sub> Max. DC Reverse Voltage (V)	30	
V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V)		

# Absolute Maximum Ratings

	Parameters	30WQ	Units	Conditions		
I <sub>F(AV)</sub>	Max. Average Forward Current *See Fig. 5	3.5	Α	50% duty cycle @ T <sub>C</sub> = 134°C, r	ectangular wave form	
I <sub>FSM</sub>	Max. Peak One Cycle Non-Repetitive	535	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and wit	
	Surge Current *See Fig. 7	90	^	10ms Sine or 6ms Rect. pulse	rated V <sub>RRM</sub> applied	
E <sub>AS</sub>	Non-Repetitive Avalanche Energy	8	mJ	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 Amps, L = 4 mH		
I <sub>AR</sub>	Repetitive Avalanche Current	1.0	А	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		

# **Electrical Specifications**

	Parameters		30WQ	Units	Conditions		
V <sub>FM</sub>	Max. Forward Voltage	Drop	0.45	V	@ 3A	T,= 25 °C	
	* See Fig. 1	(1)	0.52	V	@ 6A	1 <sub>J</sub> = 25 C	
			0.35	V	@ 3A	T <sub>1</sub> = 125 °C	
			0.46	V	@ 6A	1 <sub>J</sub> 120 0	
I <sub>RM</sub>	Max. Reverse Leakage	Current	2	mA	T <sub>J</sub> = 25 °C	V = rated V	
	* See Fig. 2	(1)	50	mA	T <sub>J</sub> = 125 °C	V <sub>R</sub> = rated V <sub>R</sub>	
V <sub>F(TO</sub>	Threshold Voltage		0.22	V	$T_J = T_J \text{ max.}$		
r <sub>t</sub>	Forward Slope Resista	nce	32.86	mΩ	7		
C <sub>T</sub>	Typical Junction Capac	citance	290	pF	$V_R = 5V_{DC}$ , (test signal range 100Khz to 1Mhz) 25 °C		
L <sub>s</sub>	Typical Series Inductar	nce	5.0	nH	Measured lead to lead 5mm from package body		
dv/dt	Max. Voltage Rate of C	Change	10000	V/µs	(Rated V <sub>R</sub> )		

(1) Pulse Width < 300µs, Duty Cycle < 2%

### Thermal-Mechanical Specifications

	<u> </u>			
	Parameters	30WQ	Units	Conditions
T <sub>J</sub>	Max. Junction Temperature Range (*)	-40 to 150	°C	
T <sub>stg</sub>	Max. Storage Temperature Range	-40 to 150	°C	
R <sub>thJC</sub>	Max. Thermal Resistance Junction to Case	4.7	°C/W	DC operation *See Fig. 4
wt	Approximate Weight	0.3 (0.01)	g (oz.)	
	Case Style	D-PAK		Similar to TO-252AA
	Marking Device	30WQ03FN		

 $<sup>\</sup>frac{\binom{*}{d}}{dT_j} < \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink

100

0.1

0.01

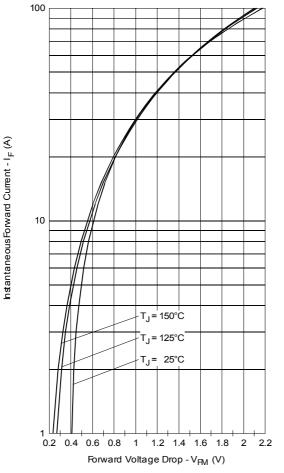
100 <sup>\_</sup> 0

Reverse Current - IR (mA)

T<sub>J</sub>= 150°C

100°C 75°C 50°C

> \_ 25°C



0.001

5 10 15 20 25 30

Reverse Voltage - V<sub>R</sub> (V)

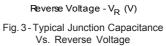
Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

1000

T<sub>J</sub> = 25°C

10 15 20 25

Fig. 1 - Maximum Forward Voltage Drop Characteristics



30

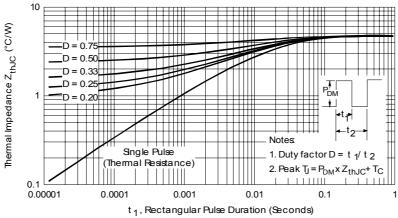


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

Document Number: 93312

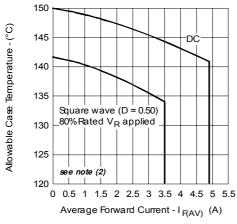


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

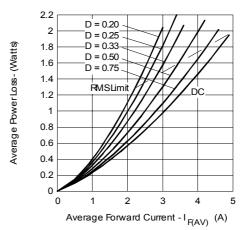


Fig. 6-Forward Power Loss Characteristics

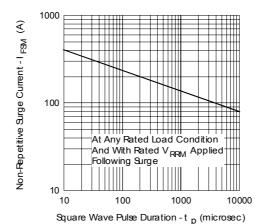
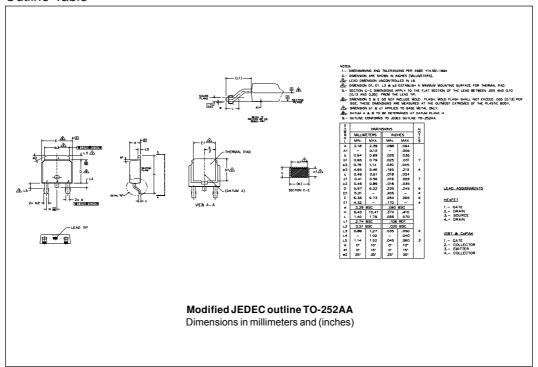


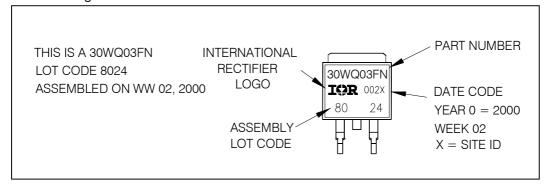
Fig. 7 - Maximum Non-Repetitive Surge Current

 $\begin{aligned} \textbf{(2)} \ \ &\text{Formula used:} \ &\text{$T_C$} = \text{$T_J$} - (\text{Pd} + \text{Pd}_{\text{REV}}) \times \text{$R_{\text{thJC}}$}; \\ &\text{$Pd$} = \text{Forward Power Loss} = \text{$I_{F(AV)}$} \times \text{$V_{\text{FM}} @ (I_{F(AV)}$} / D) \ \ (\text{see Fig. 6}); \\ &\text{$Pd_{\text{REV}}$} = \text{Inverse Power Loss} = \text{$V_{\text{R1}}$} \times \text{$I_{\text{R}}$} (1-D); \ I_{\text{R}} @ V_{\text{R1}} = 80\% \ \text{rated $V_{\text{R}}$}. \end{aligned}$ 

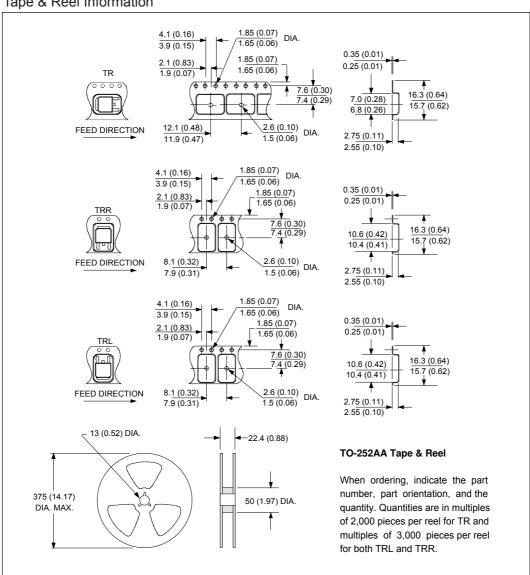
### Outline Table



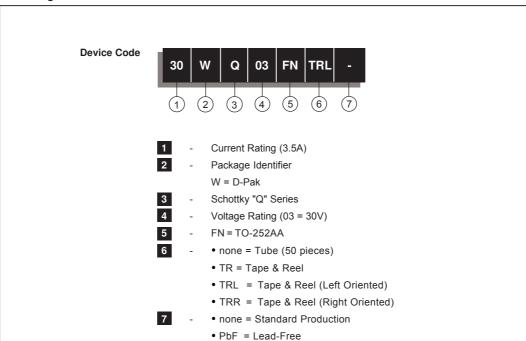
### Part Marking Information



Tape & Reel Information



#### Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level.

Qualification Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309

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Vishay

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